A Legacy of Innovation

KIOXIA¹ delivers flash-based products for next generation storage applications. With a steadfast commitment to technology innovation, KIOXIA will continue to push the boundaries of what's possible.

A LOOK BACK: OVER THREE DECADES OF INNOVATION2

1987

Invented NAND Flash Memory



1991

World's 1st Mass Production of NAND Flash Memory





1st to Introduce Commercial 1Gb MLC NAND



INNOVATION STARTS WITH KIOXIA



2007

 World's 1st 3D Flash Memory Technology Announced







2013

World's first UFS Introduced



2014

World's 1st 15nm 128Gb NAND Flash Memory Introduced



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2015

World's 1st 48-layer 3D Flash Memory

THE INVENTOR

OF FLASH MEMORY



"Changing the world through innovative solutions."

Nobuo Hayasaka President and CEO, KIOXIA Corporation

2017



 1st to Introduce 4-bit-per-cell Technology (QLC BiCS FLASH 3D Flash Memory)

2018

Mass Production of 96layer 3D Flash Memory



 Achieved Industry's Highest Capacity of 1.33 Terabits for a single chip (QLC BiCS FLASH)



2019

1st to Sample UFS Version 3.0



By 2024, worldwide data volume is expected to reach ____143 zettabytes (source IDC³)

KIOXIA Makes Data Work – Innovation in Action

2020

Introduced 112-Layer 3D Flash Memory Technology